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Light-Emitting Devices, Materials, and Applications XXIV

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Michael R. Krames
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Contents

vii *Authors*
ix *Conference Committee*

MICRO LED DISPLAY

11302 02 **Emissive displays with transfer-printed microscale LEDs and ICs (Invited Paper)** [11302-1]

11302 04 **Mojo Vision NanoLEDs for Invisible Computing (Invited Paper)** [11302-3]

NOVEL ELECTROLUMINESCENT SEMICONDUCTOR MATERIALS AND DEVICES FOR SSL I

11302 08 **High intensity photodegradation of lead halide perovskite nanocrystals** [11302-7]

LED APPLICATIONS AND SOLID-STATE LIGHTING

11302 0A **Challenges and improvements in LED-pumped luminescent concentrators** [11302-9]

11302 0B **Limitations to emission spot size in laser lighting** [11302-10]

11302 0C **Analysis and design of extreme intensity irradiation devices for research applications**
[11302-11]

11302 0D **OpticStudio TrueFreeform™ optimization for complex illumination systems** [11302-12]

NANOMATERIALS AND NANOSTRUCTURES FOR LEDs

11302 0H **Nano structured light emitting diodes through 3D mold (Invited Paper)** [11302-16]

LED MANUFACTURING/EPITAXIAL GROWTH

11302 0N **Challenges and opportunities of MOVPE and THVPE/HVPE for nitride light emitting devices (Invited Paper)** [11302-22]

NOVEL ELECTROLUMINESCENT SEMICONDUCTOR MATERIALS AND DEVICES FOR SSL II

11302 0P **WS₂ monolayer based light emitting devices fabricated by scalable deposition techniques (Invited Paper)** [11302-24]

EFFICIENCY CHALLENGES IN III-NITRIDE LEDS

11302 0X **Dependence of degradation on InGaN quantum well position: a study based on color coded structures** [11302-32]

NIR/IR-EMITTING LEDS

11302 0Y **Red surface-emitting SLEDs (Invited Paper)** [11302-33]

11302 0Z **Tunable spectral asymmetry at the facets of a chirped tapered quantum-dot superluminescent diode** [11302-34]

11302 12 **Fast-responding mid-IR light emitter using suspended multilayer graphene** [11302-37]

LIGHT-BASED SENSORS AND COMMUNICATION

11302 13 **Advanced LiFi technology: laser light (Invited Paper)** [11302-38]

11302 14 **Bidirectional data transfer in VLC links** [11302-39]

11302 16 **Automotive LiDAR pollution detection system based on total internal reflection techniques** [11302-41]

UV/DUV LEDS AND THEIR APPLICATIONS

11302 1F **Hermetic SMD-type reflector cavity packaging for DUV LEDs** [11302-49]

WAVELENGTH CONVERSION MATERIALS AND COMPONENTS

11302 1M **Paving the way to the high-performance red phosphor SALON (Invited Paper)** [11302-79]

11302 1N **Static ceramic phosphor assemblies for high-power, high-luminance SSL-light sources for digital projection and specialty lighting** [11302-53]

11302 1O **Static crystal phosphor for high power projection applications** [11302-54]

NOVEL TECHNOLOGIES FOR LED DESIGN AND FABRICATION

11302 1P **Photonic crystal based control of directionality in GaN based LEDs (Invited Paper)** [11302-58]

11302 1R **Coupling of WGM modes of two ZnO microspheres in contact: experiment and simulation**
[11302-60]

11302 1S **Laser-excited phosphor light recycling using parabolic reflectors** [11302-61]

POSTER SESSION

11302 1U **High-precision color uniformity based on 4D transformation for micro-LED** [11302-63]

11302 1V **Advanced optical characterization of automotive interior materials for premium visual quality**
[11302-64]

11302 1W **Experimental and theoretical investigation of Mn-doped CsPbCl₃ with orange light emission**
[11302-65]

11302 1X **Green light emission in CsPbBr₃ quantum dots: theoretical and experimental insight** [11302-66]

11302 1Z **Strong crystal field splitting and polarization dependence observed in the emission from Eu³⁺ ions doped into GaN** [11302-68]

11302 21 **Characterization of micro-pixelated InGaP/AlGaInP quantum well structures** [11302-70]

11302 26 **Reconstruction method of gradient-index field with background-oriented schlieren** [11302-75]

Authors

Numbers in the index correspond to the last two digits of the seven-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first five digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Abdelbaky, Mohamed, 0P
Andrzejewski, Dominik, 0P
Arimura, T., 0N
Austin, H., 1Z
Bacher, Gerd, 0P
Bailey, Christopher G., 08
Baken, Jannie, 0A
Bardella, Paolo, 0Z
Barnes, Jean-Paul, 21
Beckmann, Yannick, 0P
Ben Bakir, Badhise, 21
Benoy, Dany, 0A
Bjarlin Jensen, Ole, 0B
Blankenbach, K., 1V
Bonafede, S., 02
Boussadi, Younes, 21
Bower, C. A., 02
Bruls, Dominique, 0A
Caria, Alessandro, 0X
Cataluna, Maria Ana, 0Z
Chakrabarti, Subhananda, 1W, 1X
Chang, Yia-Chung, 1R
Chang, Yung Peng, 1O
Charlton, Martin D. B., 08, 1P
Chien, Ching-Hang, 1R
Copelman, S., 1Z
Dalla Torre, Francesco, 0X
De Santi, Carlo, 0X
Dierolf, V., 1Z
Dongre, Suryansh, 1W, 1X
Dughiero, Fabrizio, 0C
Durlinger, Ivo, 0A
Ferrandis, Philippe, 21
Forrest, Adam F., 0Z
Forzan, Michele, 0C
Fujii, Takeo, 12
Fujiwara, Y., 1Z
Gay, Shawn, 0D
Gomez-Iglesias, Alvaro, 0Y
Grundmann, Annika, 0P
Gyenge, Oliver, 1F
Haas, Harald, 13
Haenen, Ludo, 0A
Hagemann, Volker, 1N
Hansen, Anders Kragh, 0B
Hansen, Ulli, 1F
Hertlein, F., 1V
Heuken, Michael, 0P
Hoelen, Christoph, 0A
Hoerder, Gregor J., 1M
Hu, Xiaodong, 1F
Huppertz, Hubert, 1M
Ichikawa, S., 1Z
Ikeda, Katsumoto, 0D
Islim, Mohamed Sufyan, 13
Ito, Yoshinobu, 12
Jansen, Jan, 0A
Jentsch, Bruno, 0Y
Jian, Xu, 0B
Kadijk, Simon, 0A
Kalisch, Holger, 0P
Kanaras, Antonios G., 08
Keum, Changmin, 1U
Keur, Wilco, 0A
Kim, Chanyul, 1U
Kim, Je Won, 0H
Kim, Kwangdon, 1U
Koop, K., 1V
Koseki, S., 0N
Krakowski, Michel, 0Z
Krasnoshchoka, Anastasiia, 0B
Krishnan, Chirenjeevi, 1P
Krongard, B., 02
Kumar, Abhishek, 1W, 1X
Kümmell, Tilmar, 0P
Lagoudakis, Pavlos G., 08, 1P
Lee, Changmin, 13
Li, Kenneth, 1O, 1S
Licitra, Christophe, 21
Lim, Taegyu, 1U
Liu, Chia-Liang, 1R
Louro, P., 14
Marti, Dominik, 0B
Martin, Paul S., 04
Marx, Sebastian, 1F
Masenelli, Bruno, 21
Matsumoto, K., 0N
Maus, Simon, 1F
McLaurin, Melvin, 13
Meitl, M. A., 02
Meneghesso, Gaudenzio, 0C, 0X
Meneghini, Matteo, 0C, 0X
Mercier, Thomas M., 08, 1P
Mishima, A., 0N
Mitchell, B., 1Z
Mos, Barry, 0A
Musselman, Kevin, 0P
Nagata, Takaaki, 12

Najjba, F., 1V
Nakamura, Tenkai, 12
Neumann, Cornelius, 16
Ohno, Hiroshi, 26
Pandey, Nivedita, 1W, 1X
Park, Cheolseong, 1U
Park, Seihan, 1U
Pearson, A., 02
Peterseim, Tobias, 16
Petersen, Paul Michael, 0B
Pizzolato, Alberto, 0C
Poplawsky, J. D., 1Z
Queisser, Marco, 1F
Radauscher, E., 02
Raring, James, 13
Raymond, B., 02
Reichel, S., 1V
Renso, Nicola, 0X
Rochat, Névine, 21
Rudy, Paul, 13
Sasaki, Tatsuaki, 12
Seidl, Albrecht, 1N
Shah, Binith, 13
Shaw, Peter J., 08, 1P
Sparks, Adrian, 13
Suyama, Motohiro, 12
Tatebayashi, J., 1Z
Thorseth, Anders, 0B
Timmerman, D., 1Z
Tokunaga, H., 0N
Tomita, Y., 0N
Tonkikh, Alexander, 0Y
Trierweiler, Manuel, 16
Trivellin, Nicola, 0C
Ulrich, M., 1V
van Grunsven, Eric, 0A
Verreen, C., 02
Vescan, Andrei, 0P
Vick, E., 02
Videv, Stefan, 13
Vieira, M. A., 14
Vieira, M., 14
Waite, M., 1Z
Weeks, T., 02
Weidmann, Günter, 1N
Witzigmann, Bernd, 0Y
Yamaguchi, A., 0N
Yamaoka, Y., 0N
Yano, Y., 0N
Yeow, Travis, 0P
Yu, Joan, 0A
Zanoni, Enrico, 0C, 0X
Zecchin, Lorenzo, 0X

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Session Chairs

- 1 Micro LED Display
Michael R. Krames, Arkesso, LLC (United States)
Jim R. Bonar, Facebook Technologies, LLC (United States)
- 2 Novel Electroluminescent Semiconductor Materials and Devices for SSL I
Martin Strassburg, OSRAM Opto Semiconductors GmbH (Germany)
- 3 LED Applications and Solid-State Lighting
Jong Kyu Kim, Pohang University of Science and Technology (Korea, Republic of)
- 4 Nanomaterials and Nanostructures for LEDs
Aurelien David, Soraa, Inc. (United States)
- 5 2D Optoelectronics Materials
Debdeep Jena, Cornell University (United States)
- 6 LED Manufacturing/Epitaxial Growth
Martin Strassburg, OSRAM Opto Semiconductors GmbH (Germany)
- 7 Novel Electroluminescent Semiconductor Materials and Devices for SSL II
Soo Min Lee, Veeco Instruments Inc. (United States)
- 8 Efficiency Challenges in III-Nitride LEDs
Aurelien David, Soraa, Inc. (United States)
Michael R. Krames, Arkesso, LLC (United States)
- 9 NIR/IR-Emitting LEDs
Changmin Lee, SLD Laser (United States)
- 10 Light-Based Sensors and Communication
Bernd Witzigmann, University Kassel (Germany)
- 11 Novel Substrates and UV/DUV LEDs and their Applications
Masafumi Jo, RIKEN Center for Brain Science (Japan)
- 12 UV/DUV LEDs and Their Applications
Tetsuya Takeuchi, Meijo University (Japan)

- 13 Quantum-Dot Based LEDs
Juanita N. Kurfin, OSRAM Opto Semiconductors Inc. (United States)
- 14 Wavelength Conversion Materials and Components
Marie Anne van de Haar, Seaborough Research B.V. (Netherlands)
- 15 Novel Technologies for LED Design and Fabrication
Je Won Kim, Namseoul University (Korea, Republic of)

